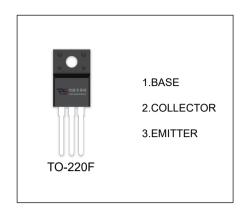


KTA1659A TRANSISTOR (PNP)

FEATURES

- High Transition Frequency
- High Voltage Applications
- Complementary to KTC4370A



MAXIMUM RATINGS (T_a=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	-180	V
V _{CEO}	Collector-Emitter Voltage	-180	V
V _{EBO}	Emitter-Base Voltage	-5	V
Ic	Collector Current	-1.5	Α
Pc	Collector Power Dissipation	2	W
R _{0JA}	Thermal Resistance From Junction To Ambient	62.5	°C/W
T _J ,T _{stg}	Operation Junction and Storage Temperature Range	-55~+150	$^{\circ}$

ELECTRICAL CHARACTERISTICS (T_a=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _C =-100μΑ,I _E =0	-180			V
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _C =-10mA,I _B =0	-180			V
Emitter-base breakdown voltage	V _{(BR)EBO}	O I _E =-1mA,I _C =0				V
Collector cut-off current	I _{CBO}	V _{CB} =-160V,I _E =0			-1	μA
Emitter cut-off current	I _{EBO}	V _{EB} =-5V,I _C =0			-1	μA
DC current gain	h _{FE}	V _{CE} =-5V, I _C =-100mA	70		240	
Collector-emitter saturation voltage	V _{CE(sat)}	I _C =-500mA,I _B =-50mA			-1.5	V
Base-emitter voltage	V _{BE}	V _{CE} =-5V, I _C =-500mA			-1	V
Collector output capacitance	C _{ob}	V _{CB} =-10V,I _E =0, f=1MHz		30		pF
Transition frequency	f _T	Vc=-10V,Ic=-100mA		100		MHz

CLASSIFICATION OF h_{FE}

RANK	0	Υ
RANGE	70-140	120-240



